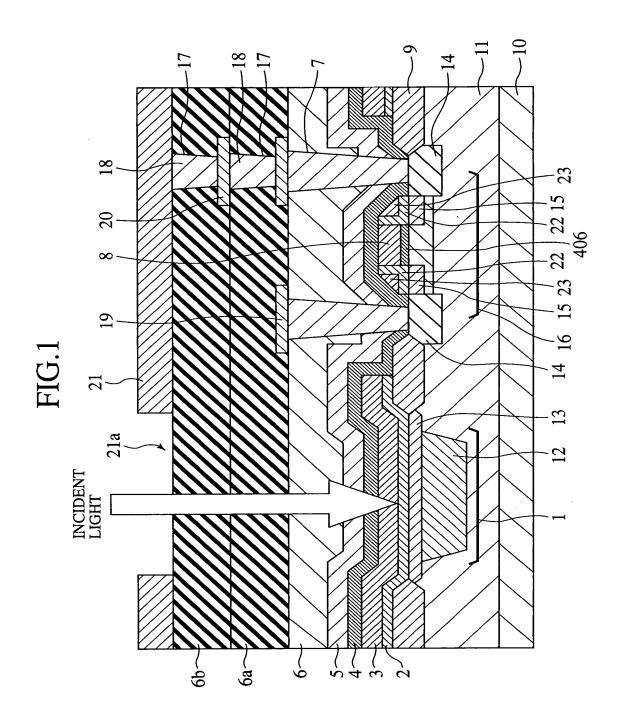
APPLN. FILING DATE: JULY 10, 2003
TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR
INVENTOR(S): TAKASHI TOYODA ET AL.
ATTORNEY DOCKET NO: 027260-668
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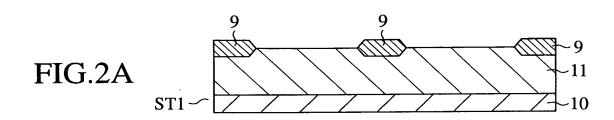


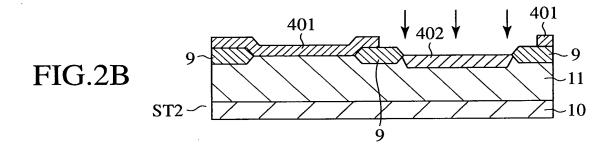
APPLN. FILING DATE: JULY 10, 2003 TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR

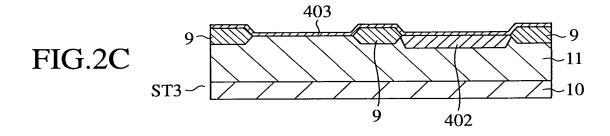
INVENTOR(S): TAKASHI TOYODA ET AL. ATTORNEY DOCKET NO: 027260-668

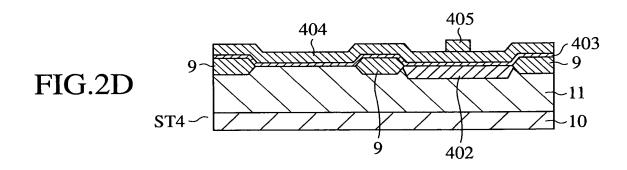
SHEET 2 of 8

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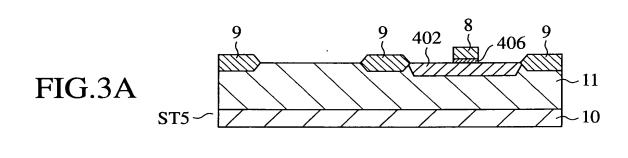
TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR

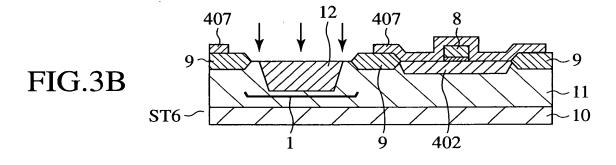
INVENTOR(S): TAKASHI TOYODA ET AL.

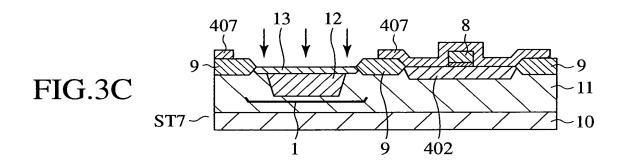
**ATTORNEY DOCKET No: 027260-668** 

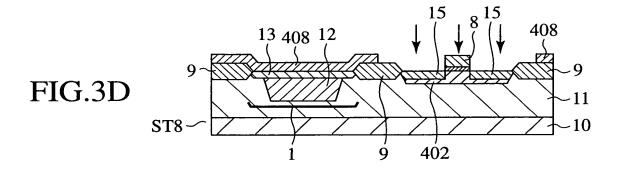
SHEET 3 of 8

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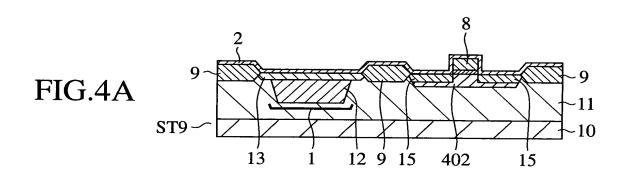


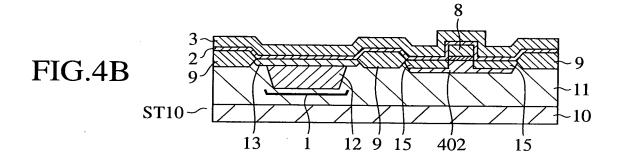
TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR

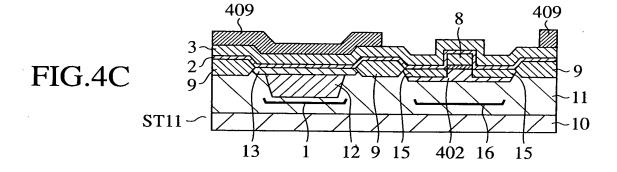
INVENTOR(S): TAKASHI TOYODA ET AL. ATTORNEY DOCKET NO: 027260-668

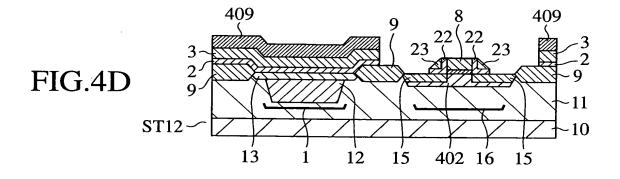
SHEET 4 of 8

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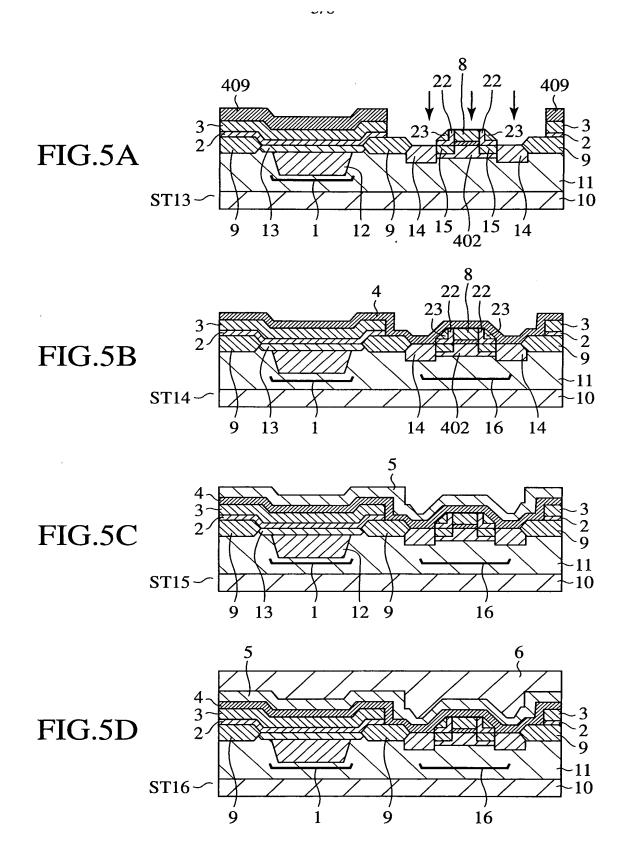




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INVENTOR(S): TAKASHI TOYODA ET AL. ATTORNEY DOCKET NO: 027260-668

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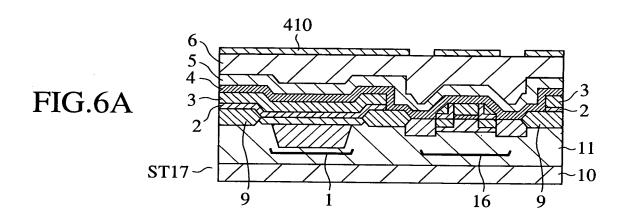


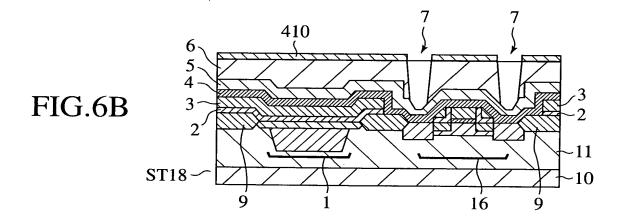
APPLN. FILING DATE: JULY 10, 2003 TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR

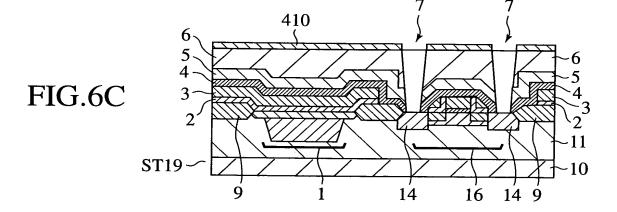
INVENTOR(S): TAKASHI TOYODA ET AL. ATTORNEY DOCKET NO: 027260-668

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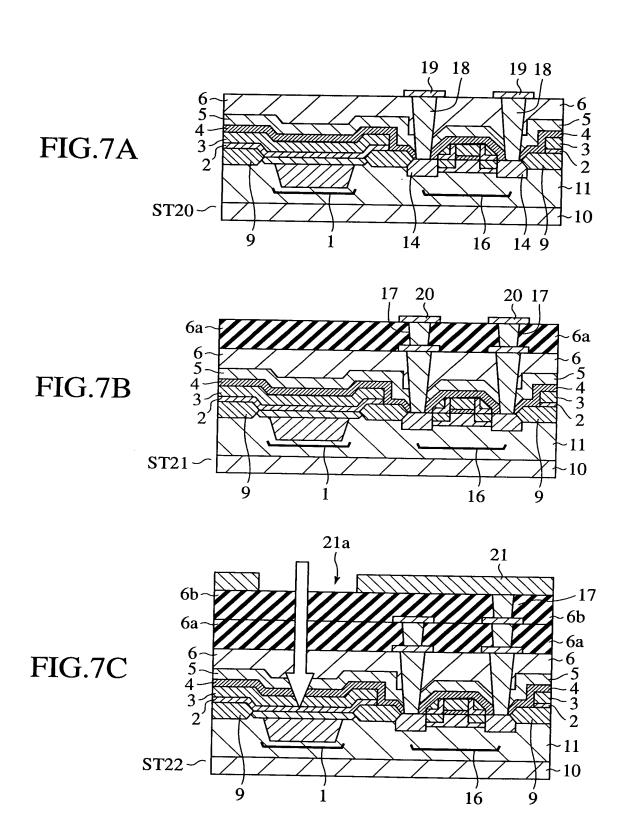


APPLN. FILING DATE: JULY 10, 2003
TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR

INVENTOR(S): TAKASHI TOYODA ET AL. ATTORNEY DOCKET NO: 027260-668

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TITLE: PRODUCING METHOD OF CMOS IMAGE SENSOR

INVENTOR(S): TAKASHI TOYODA ET AL.

ATTORNEY DOCKET NO: 027260-668

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FIG.8A

Si/OXIDE FILM ONLY

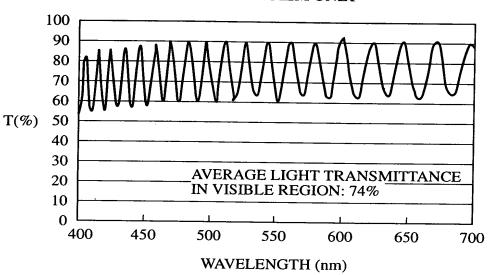


FIG.8B

Si/OXIDE FILM 10nm/NITRIDE FILM 70nm/OXIDE FILM 20nm /NITRIDE FILM 50nm/OXIDE FILM

